



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT

SCHOTTKY DIODE

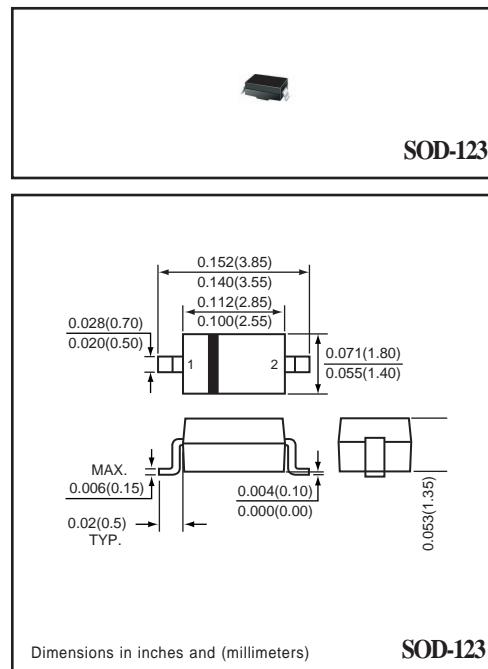
VOLTAGE 100 Volts CURRENT 75 mAmpere

BAT46BGP

FEATURE
* Small surface mounting type. (SOD-123)
* Suitable for high packing density.
* Maximum total power dissipation is 200mW.
* Peak forward current is 500mA at time<1.0sec.

CONSTRUCTION
* Silicon epitaxial planar
MARKING
* BT3

CIRCUIT



RATINGS	SYMBOL	BAT46BGP	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	100	Volts
Maximum RMS Voltage	V _{RMS}	70	Volts
Maximum DC Blocking Voltage	V _D	100	Volts
Maximum Average Forward Rectified Current	I _o	75	mAmps
Peak Forward Surge Current at <10mSec.	I _{FSM}	0.75	Amps
Typical Junction Capacitance between Terminal (Note 1)	C _J	10	pF
Power Dissipation	P _d	200	mW
Maximum Operating Temperature Range	T _J	+125	°C
Storage Temperature Range	T _{STG}	-55 to +125	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	BAT46BGP	UNITS
Maximum Instantaneous Forward Voltage I _F = 0.1mA I _F = 10mA I _F = 250mA	V _F	250 450 1000	mVolts
Maximum Average Reverse Current at V _R = 75V	I _R	5.0	uAmps

- NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 1.0 volts.
 2. Measured at applied forward current of 10mA and reverse current of 10mA.
 3. ESD sensitive product handling required.

2012-05